

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S186	210	(gallium near2 nitride gan) near2 (sapphire or "al.sub.2o.sub.3") near2 (si or silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/06 15:24
S188	9609	(sapphire or "al.sub.2o.sub.3") near10 (si or silicon) near10 (wafer or substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/06 15:31
S187	143	(bow\$4 or warp\$5) near15 wafer and (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/06 15:31
S189	29	(sapphire or "al.sub.2o.sub.3") near10 (si or silicon) near10 (wafer or substrate) near10 layered	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/06 15:33
S191	58	matt\$4 near2 song	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/06 15:43
S190	34	(sapphire or "al.sub.2o.sub.3") near10 (si or silicon) near10 (wafer or substrate) near10 (warp\$5 or bow\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/06 15:43
L32	104	silicon near2 tec	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/07 13:25
L33	190	silicon near2 thermal near2 expansion near2 coefficient near5 deg	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/07 13:46
L34	3	"3143026".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/07 16:00
L35	2	"53028374"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/07 16:09

L37	20	tetsuzo near2 ueda.in. and sapphire near4 silicon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/07 16:10
L36	77	tetsuzo near2 ueda.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/07 16:10